

T498C686M004ATE900

T498, Tantalum, MnO₂ Tantalum, High Temperature, 68 uF, 20%, 4 VDC, SMD, MnO₂, Molded, Hi-Temp, 150C, Auto, AEC-Q200, 900 mOhms, 2.8 mm, 2312 / 6032



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General Information

Series	T498
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Hi-Temp, 150C, Auto, AEC-Q200
Features	Automotive, 150C
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
Typical Component Weight	224.48 mg
Shelf Life	156 Weeks
MSL	1

Dimensions

L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
A	3.1mm MIN
B	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Specifications

Capacitance	68 uF
Tolerance	20%
Voltage DC	4 VDC (85C), 3.19 VDC (125C), 2.68 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5% 120Hz 25C
Failure Rate	N/A
ESR	900 mOhms (100kHz 25C)
Ripple Current	350 mA (rms, 100kHz 25C), 315 mA (rms, 85C), 105 mA (rms, 150C)
Leakage Current	2.7 uA (5min 25°C)

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

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